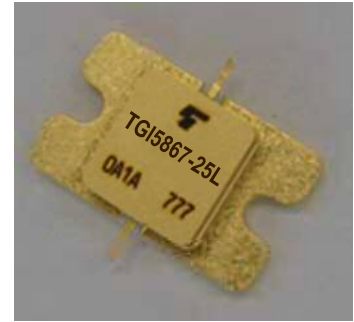


FEATURES

- **BROAD BAND INTERNALLY MATCHED HEMT**
- **HIGH POWER**
Pout= 44.5dBm at Pin= 35dBm
- **HIGH GAIN**
GL= 13.5dB at Pin= 20dBm
- **LOW INTERMODULATION DISTORTION**
IM3= -40dBc(Min.) at Pout= 29dBm (Single Carrier Level)
- **HERMETICALLY SEALED PACKAGE**



RF PERFORMANCE SPECIFICATIONS (Ta= 25°C)

CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT	MIN.	TYP.	MAX.
Output Power	Pout	VDS= 24V IDSset= 1.75A f= 5.85 to 6.75 GHz @Pin= 35dBm	dBm	44.0	44.5	—
Drain Current	IDS1		A	—	2.7	3.2
Power Added Efficiency	η_{add}		%	—	39	—
Linear Gain	GL	@Pin= 20dBm	dB	12.5	13.5	—
Gain Flatness	ΔG		dB	—	—	± 0.8
3rd Order Intermodulation Distortion	IM3	Two-Tone Test Po= 29dBm, Δf = 5MHz (Single Carrier Level)	dBc	-40	-42	—
Drain Current	IDS2		A	—	—	2.0
Channel Temperature Rise	ΔT_{ch}	$(VDS \times IDS + Pin - Pout) \times R_{th}(c-c)$	°C	—	130	150

Recommended Gate Resistance(Rg): 60 Ω

ELECTRICAL CHARACTERISTICS (Ta= 25°C)

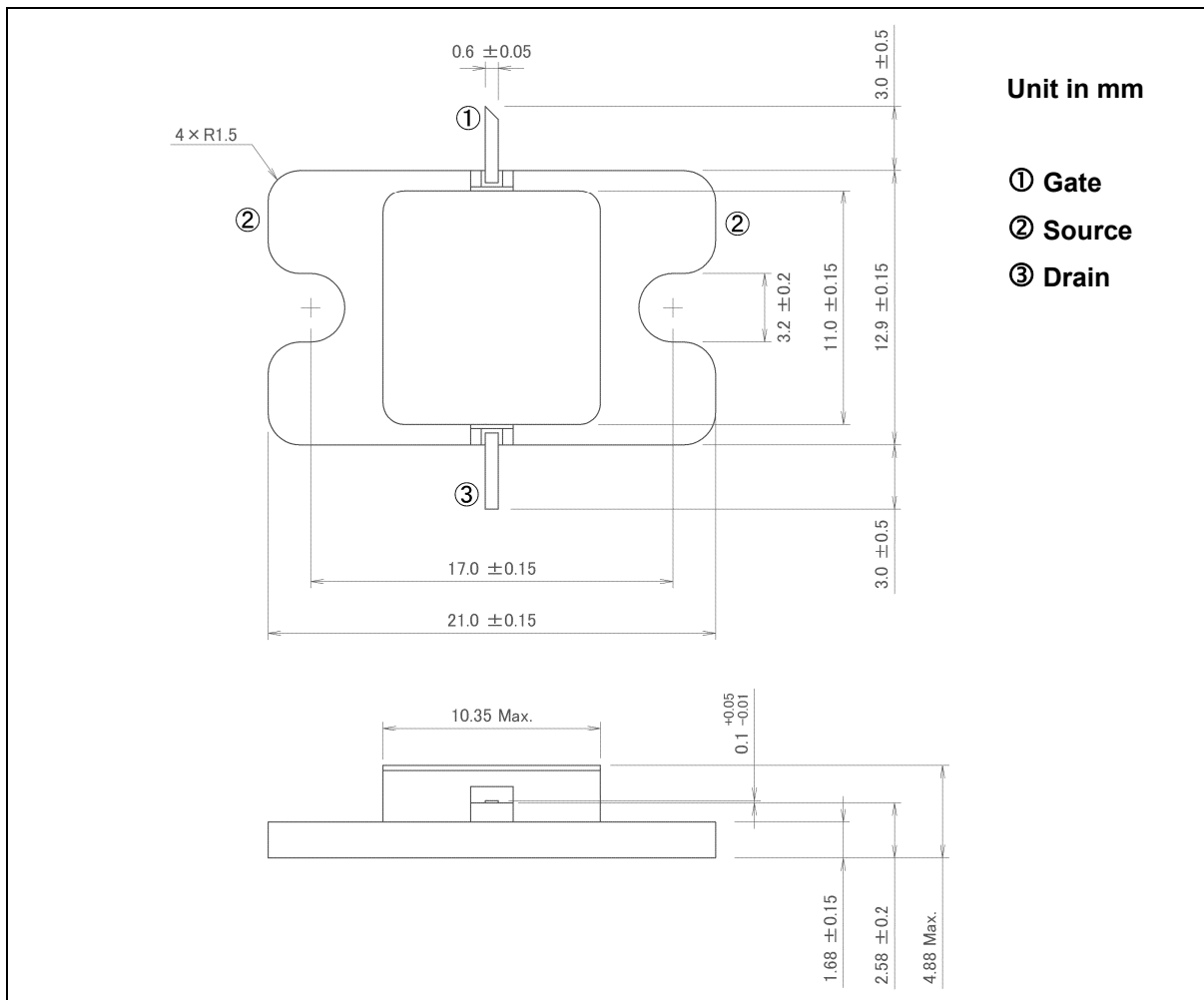
CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT	MIN.	TYP.	MAX.
Transconductance	gm	VDS= 5V IDS= 2.5A	S	—	1.2	—
Pinch-off Voltage	VGSoff	VDS= 5V IDS= 12mA	V	-2.0	-4.0	-6.0
Saturated Drain Current	IDSS	VDS= 5V VGS= 0V	A	—	7.5	—
Gate-Source Breakdown Voltage	VGSO	IGS= -5mA	V	-10	—	—
Thermal Resistance	Rth(c-c)	Channel to Case	°C/W	—	2.8	3.2

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ABSOLUTE MAXIMUM RATINGS (Ta= 25°C)

CHARACTERISTICS	SYMBOL	UNIT	RATING
Drain-Source Voltage	VDS	V	50
Gate-Source Voltage	VGS	V	-10
Drain Current	IDS	A	7.5
Total Power Dissipation (Tc= 25°C)	PT	W	70
Channel Temperature	Tch	°C	250
Storage Temperature	Tstg	°C	-65 to +175

PACKAGE OUTLINE (7-AA04A)



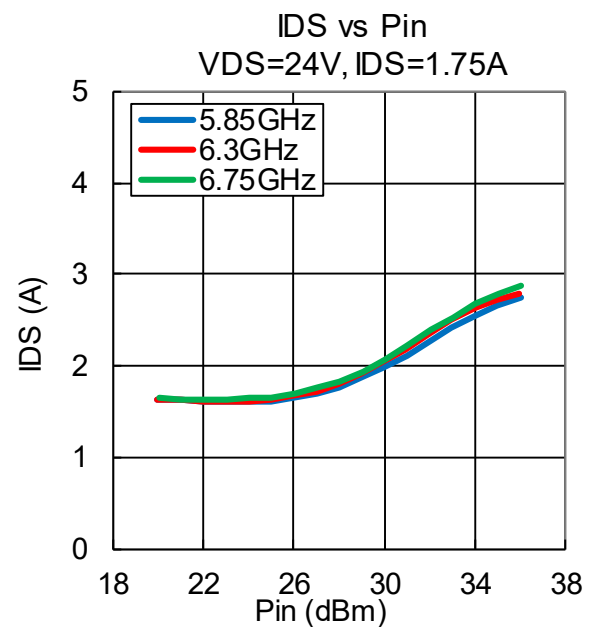
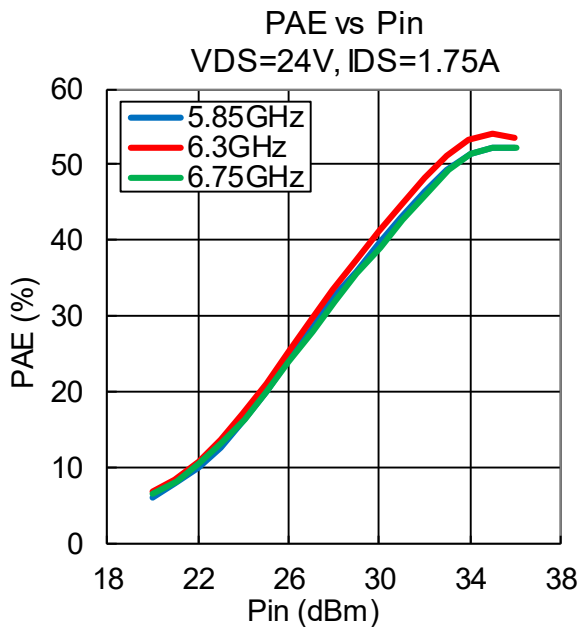
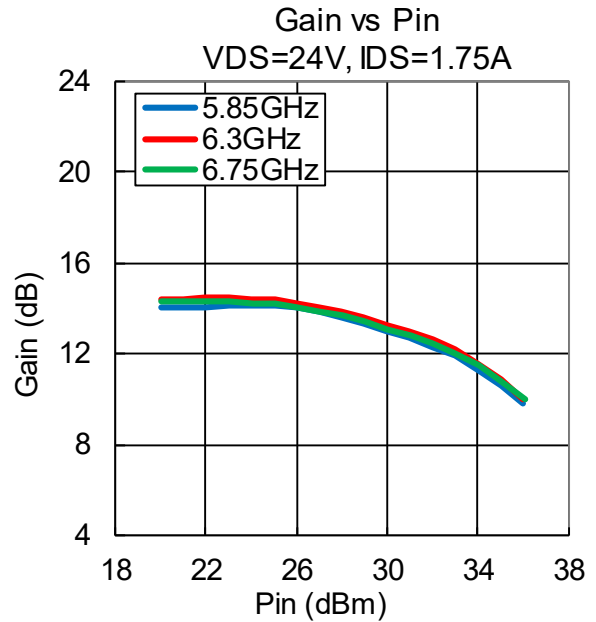
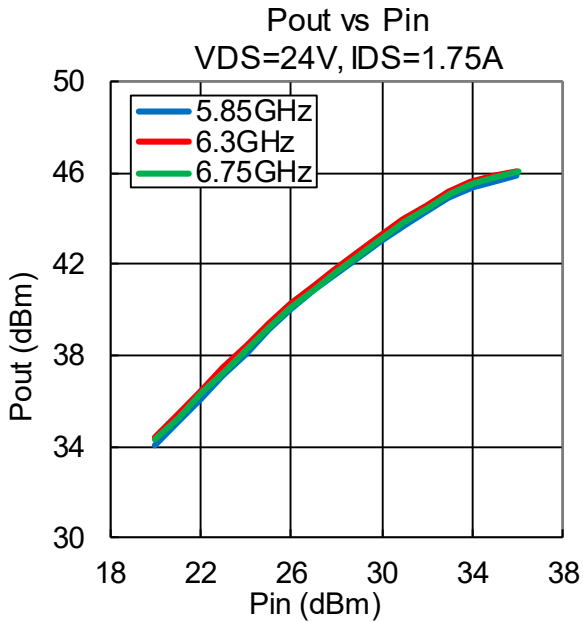
HANDLING PRECAUTIONS FOR PACKAGE MODEL

Soldering iron should be grounded and the operating time should not exceed 10 seconds at 260°C or 3 seconds at 350°C.

TYPICAL RF PERFORMANCE

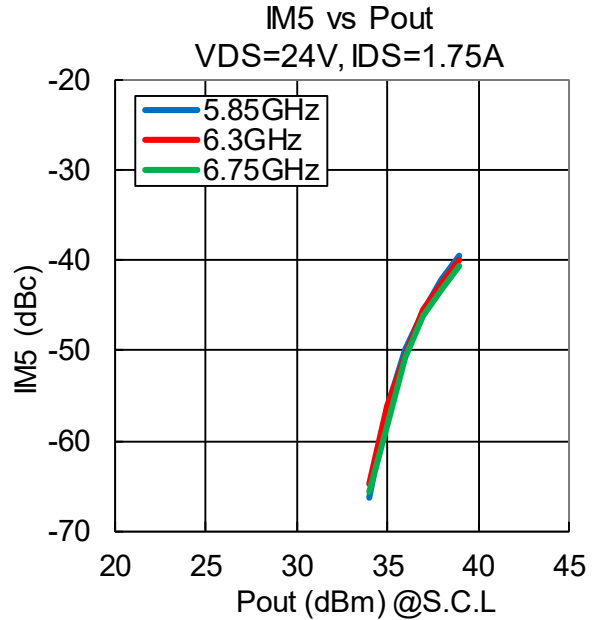
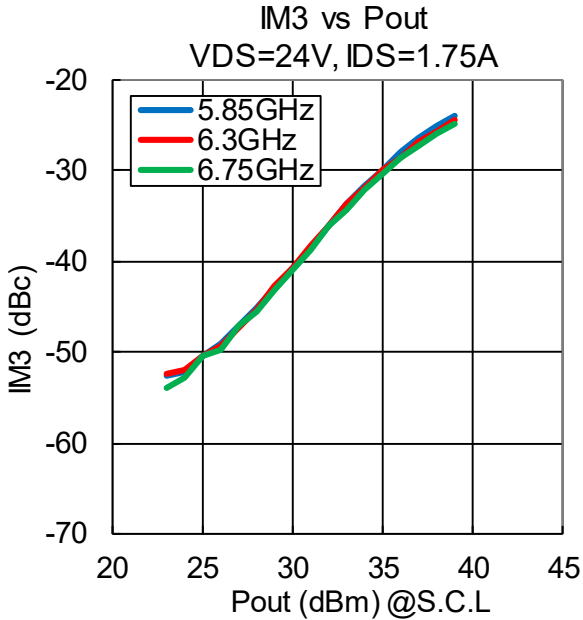
•Pout , Gain , PAE , IDS vs. Pin

VDS= 24 V, IDSset= 1.75 A, f= 5.85, 6.3, 6.75 GHz, Ta= +25 °C



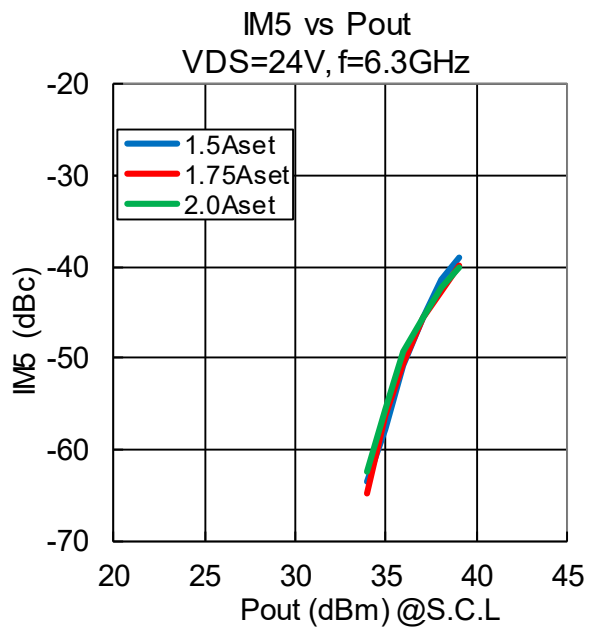
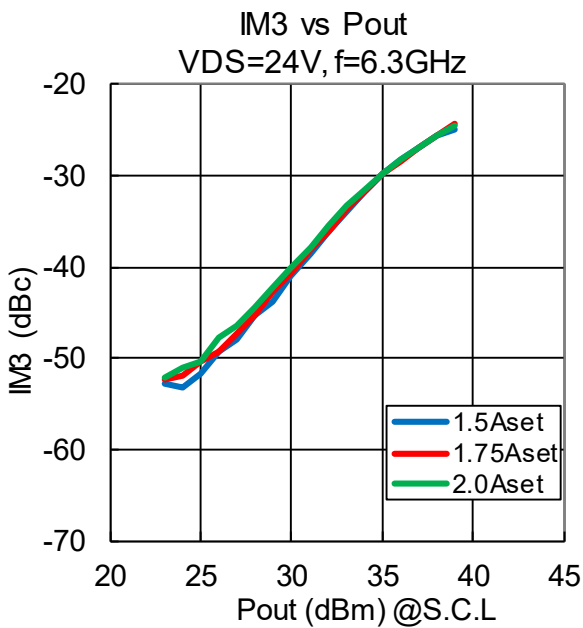
•IM3, IM5 vs. Pout

VDS= 24 V, IDSset= 1.75 A, f= 5.85, 6.3, 6.75 GHz, Δf= 5 MHz, Ta= +25 °C



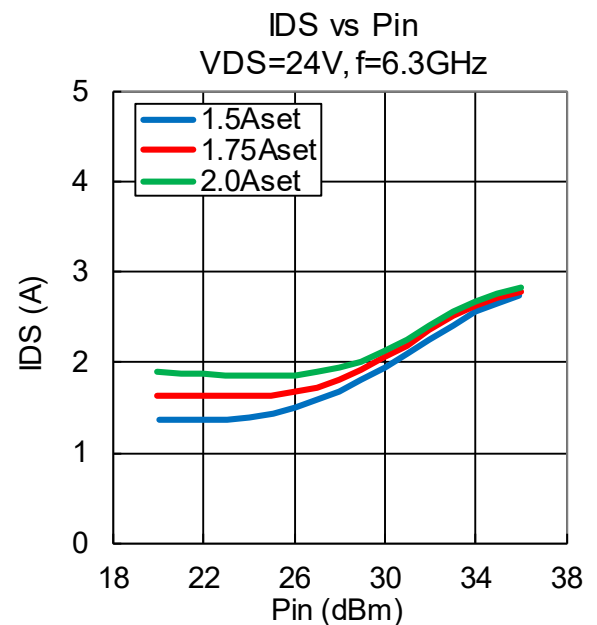
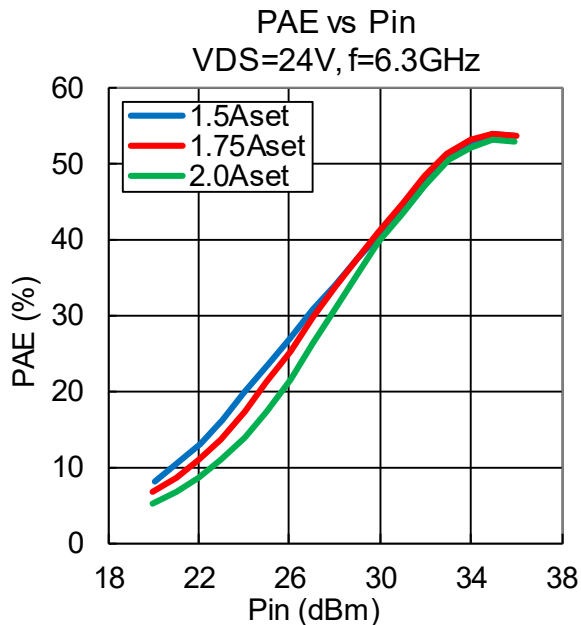
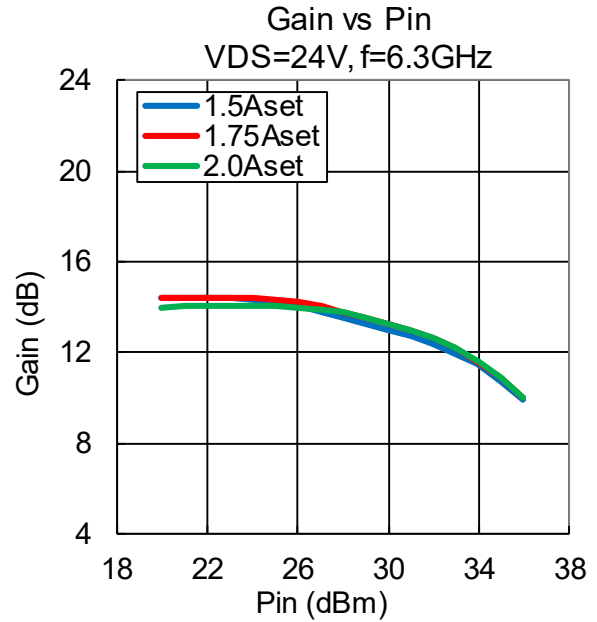
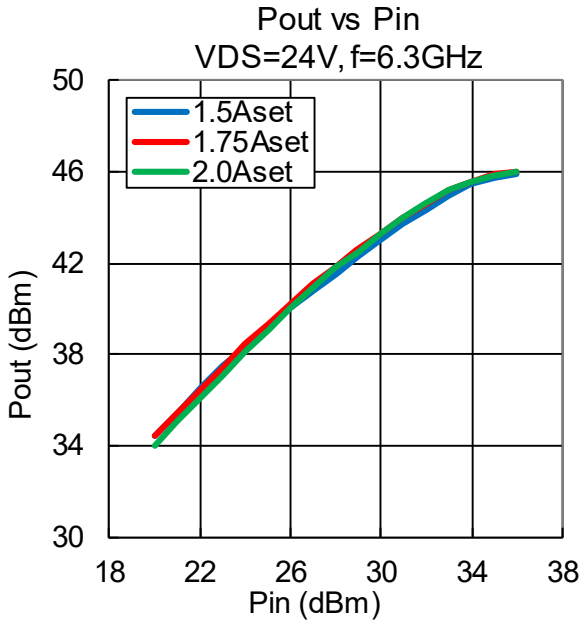
•IM3, IM5 vs. Pout

VDS= 24 V, IDSset= 1.5, 1.75, 2.0 A, f= 6.3 GHz, Ta= +25 °C



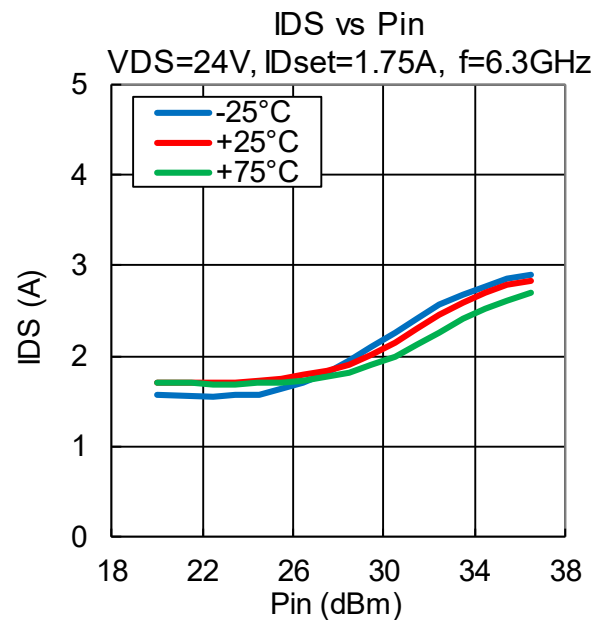
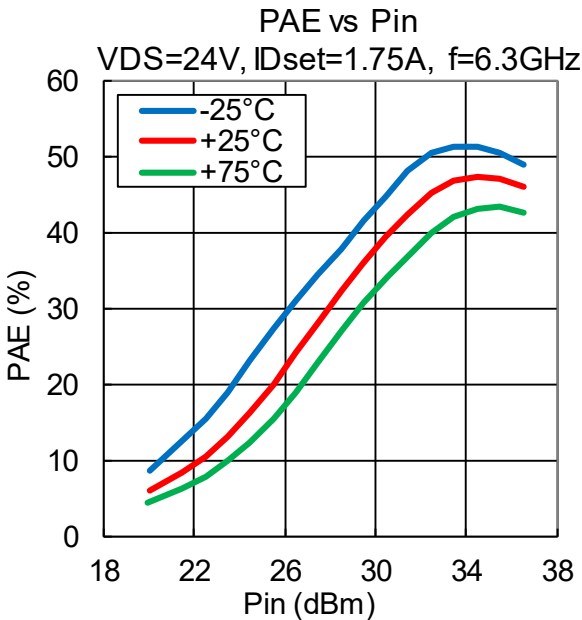
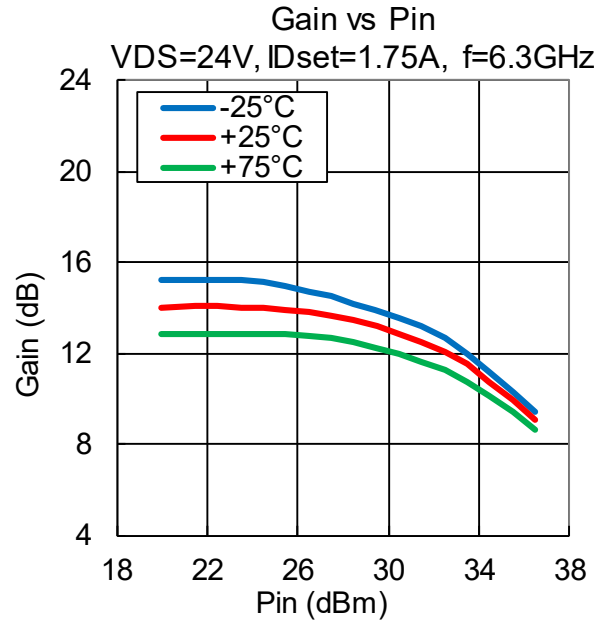
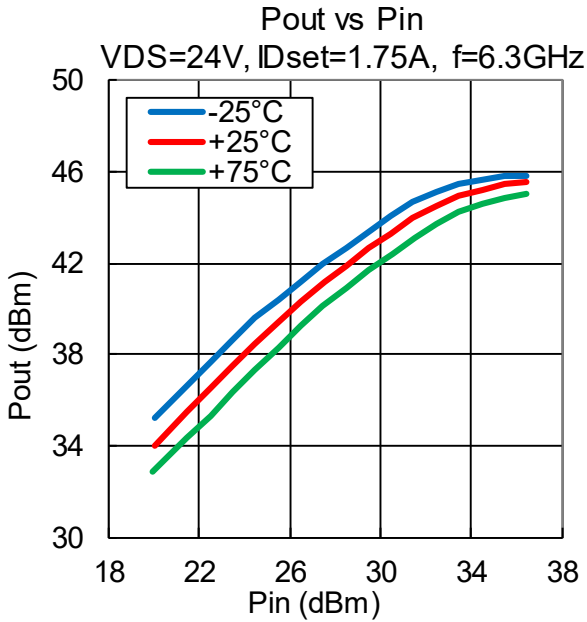
•Pout , Gain , PAE , IDS vs. Pin vs. IDSset

VDS= 24 V, IDSset= 1.5, 1.75, 2.0 A, f= 6.3 GHz, Ta= +25 °C



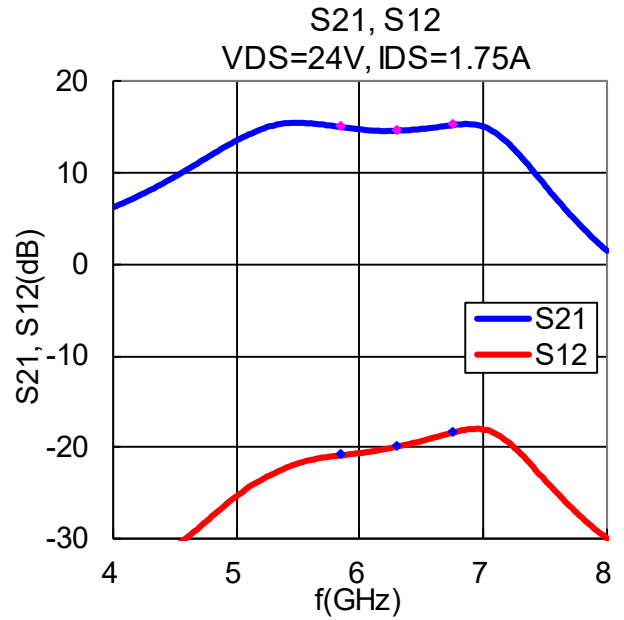
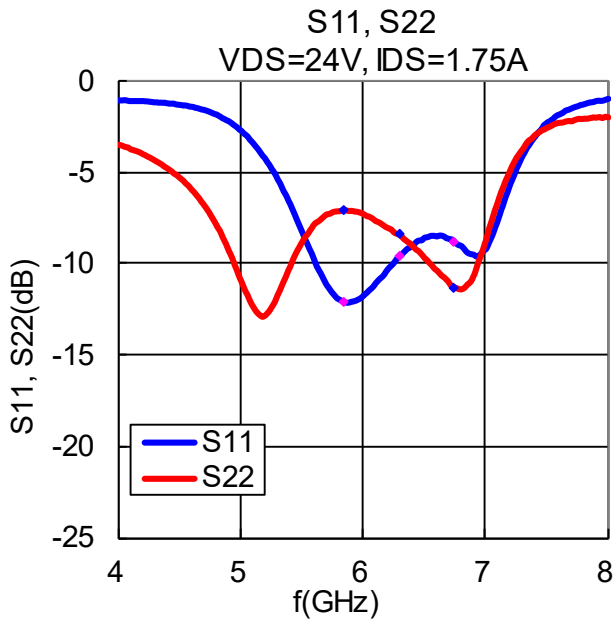
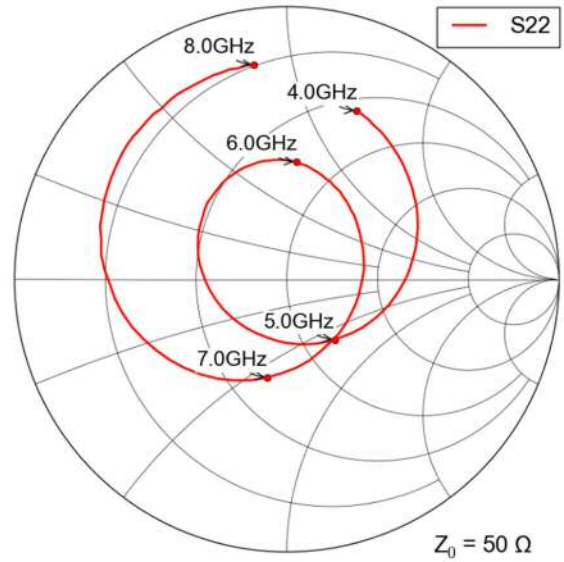
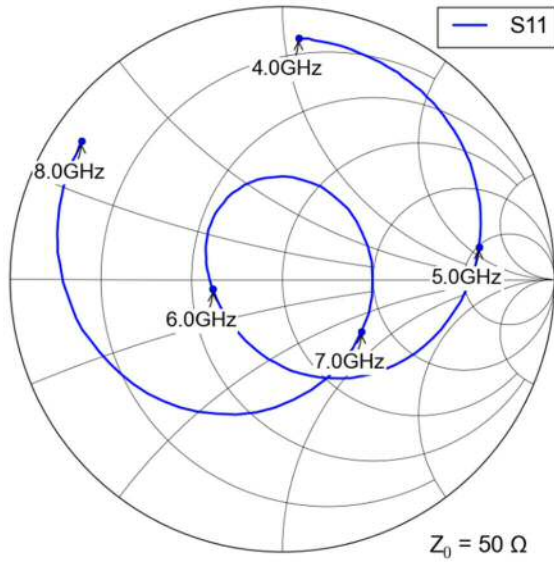
•Pout , Gain , PAE , IDS vs. Pin vs. Temperature

VDS= 24 V, IDSset= 1.75 A, f= 6.3 GHz, Ta= -25, +25, +75 °C



-S-Parameters

VDS= 24 V, IDSset= 1.75 A, f= 4.0 to 8.0 GHz, Ta= +25 °C



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